

Low- and High-Frequency Noise from Coherent Two-Level Systems

Alexander Shnirman,¹ Gerd Schön,¹ Ivar Martin,² and Yuriy Makhlin³

¹*Institut für Theoretische Festkörperphysik, Universität Karlsruhe, D-76128 Karlsruhe, Germany*

²*Theoretical Division, Los Alamos National Laboratory, Los Alamos, New Mexico 87545, USA*

³*Landau Institute for Theoretical Physics, Kosygin Street 2, 119334 Moscow, Russia*

(Received 13 January 2005; published 1 April 2005)

Recent experiments indicate a connection between the low- and high-frequency noises affecting superconducting quantum systems. We explore the possibilities that both noises can be produced by one ensemble of microscopic modes, made up, e.g., by sufficiently coherent two-level systems (TLS's). This implies a relation between the noise power in different frequency domains, which depends on the distribution of the parameters of the TLS's. We show that a distribution, natural for tunneling TLS's, with a log-uniform distribution in the tunnel splitting and linear distribution in the bias, accounts for experimental observations.

DOI: 10.1103/PhysRevLett.94.127002

PACS numbers: 74.40.+k, 03.65.Yz, 03.67.-a, 85.25.-j

Recent activities and progress with quantum information systems rely on the control of decoherence processes and at the same time provide novel tools to study their mechanisms. Experiments with superconducting qubits revealed the presence of spurious quantum two-level systems (TLS's) [1] with strong effects on the high-frequency (~ 10 GHz) qubit dynamics. Other experiments [2] suggested a connection between the strengths of the Ohmic high-frequency noise, responsible for the relaxation of the qubit (T_1 decay), and the low-frequency $1/f$ noise, which dominates the dephasing (T_2 decay). The noise power spectra, extrapolated from the low- and high-frequency sides, cross at ω of order T . This is also compatible with the T^2 dependence of the low-frequency part, observed earlier for the $1/f$ noise in Josephson devices [3,4]. Much clearer evidence for the T^2 behavior was obtained recently [5,6].

In this Letter we point out that a set of *coherent* two-level systems (or, in fact, arbitrary quantum systems with discrete spectrum) produces both high- and low-frequency noise with strengths that are naturally related. We show that for a realistic distribution of parameters tunnel TLS's (TTLS's) produce noise with experimentally detected features: the $1/f$ behavior at low frequencies, the Ohmic ($\propto \omega$) high-frequency noise, and the T^2 temperature dependence of the integrated weight of the low-frequency noise. This implies that the $1/f$ and Ohmic asymptotes cross at $\omega \sim T$ as was indeed observed in Ref. [2] at one value of T . The distribution is log uniform in the tunnel splitting and linear in the bias. Microscopically, this distribution may describe double traps or "Andreev fluctuators" considered recently by Faoro *et al.* [7] in their study of the relaxation (T_1 decay) of Josephson qubits due to the high-frequency noise. Our results are obtained for environments with a large number of TLS's which are weakly coupled to the qubit. A strong coupling between a TLS and a qubit can lead to resonances [1,2].

Ensembles of TLS's were discussed extensively in the literature. On one hand, they produce a natural model of

$1/f$ noise, as a result of *incoherent* random transitions [8], and there is substantial experimental evidence that the low-frequency $1/f$ noise in single-electron devices may be produced by TLS's [9,10]. In solid-state qubits, e.g., Josephson qubits, the pure dephasing is dominated by this noise [11–13]. On the other hand, ensembles of coherent TTLS's were suggested to explain low-temperature properties of glasses [14,15]. Both "transverse" and "longitudinal" couplings to the TLS's, defined below, were discussed in relation to various physical phenomena. A transverse coupling of phonons or electrons to the TLS's is responsible for the absorption and emission of energy. It was invoked in the discussions of, e.g., the phonon attenuation [16] and of the low-temperature dephasing in disordered metals [17]. On the other hand, a longitudinal coupling to the TLS's was found to be responsible, e.g., for the conductance fluctuations [18–20]. We suggest that in nanocircuits, e.g., solid-state qubits, both types of couplings play an important part and produce noise with related properties in various frequency ranges.

As a model we consider a set of coherent two-level systems described by the Pauli matrices $\sigma_{p,j}$, where $p = x, y, z$ and j is the index of a particular TLS. We write the Hamiltonian of the set in the basis defined by their contributions to the relevant fluctuating quantity [cf. Eq. (2) below];

$$H_{\text{TLS}} = \sum_j \left[-\frac{1}{2}(\varepsilon_j \sigma_{z,j} + \Delta_j \sigma_{x,j}) + H_{\text{diss},j} \right]. \quad (1)$$

Here, in the language of TTLS's, ε_j are the bias energies and Δ_j are the tunnel amplitudes between two states. Each TLS with label j is subject to dissipation due to its own bath with Hamiltonian $H_{\text{diss},j}$. We do not specify $H_{\text{diss},j}$ but only assume that it produces the usual relaxation (T_1) and dephasing (T_2) processes. We assume that all the TTLSs are underdamped, with $\Gamma_{1,j} \equiv T_{1,j}^{-1} \ll E_j$ and $\Gamma_{2,j} \equiv T_{2,j}^{-1} \ll E_j$. Here $E_j \equiv \sqrt{\varepsilon_j^2 + \Delta_j^2}$ is the energy splitting.

Each TLS in the ensemble contributes to fluctuations of a physical quantity X , e.g., the gate charge, which affect an experimentally accessible system and thus may be detected. A qubit may serve as a convenient noise detector [21,22]. For example, in the recent experiment of Ref. [2] qubits were used to investigate the properties of their environment. We choose

$$X \equiv \sum_j v_j \sigma_{z,j}, \quad (2)$$

where v_j are the coupling constants and $\sigma_{z,j} = \pm 1$ correspond to the two states differing, e.g., by the value of the dipole moment. The interaction of the qubit with the TLS's is often described via a linear in X coupling to a variable O_{qubit} of the qubit, i.e., $H_{\text{int}}(X) \propto X O_{\text{qubit}}$.

Our goal in the following is to investigate the noise properties of X ; that is, we need to evaluate the (unsymmetrized) correlator

$$C_X(\omega) \equiv \int dt \{ \langle X(t)X(0) \rangle - \langle X \rangle^2 \} e^{i\omega t}. \quad (3)$$

For independent TLSs the noise is a sum of individual contributions, $C_X = \sum_j v_j^2 C_j$, where

$$C_j(\omega) \equiv \int dt \{ \langle \sigma_{z,j}(t) \sigma_{z,j}(0) \rangle - \langle \sigma_{z,j} \rangle^2 \} e^{i\omega t}. \quad (4)$$

To obtain C_j we first transform to the eigenbasis of the TLS. This gives

$$H_{\text{TLS}} = \sum_j \left\{ -\frac{1}{2} E_j \rho_{z,j} + H_{\text{diss},j} \right\}, \quad (5)$$

and

$$X = \sum_j v_j (\cos\theta_j \rho_{z,j} - \sin\theta_j \rho_{x,j}), \quad (6)$$

where $\tan\theta_j \equiv \Delta_j/\epsilon_j$. The first term of (6) produces the longitudinal coupling to the TLS's (mentioned above), while the second term produces the transverse one. Using the Bloch-Redfield theory [23,24] we find readily

$$\begin{aligned} C_j(\omega) \approx & \cos^2\theta_j [1 - \langle \rho_{z,j} \rangle^2] \frac{2\Gamma_{1,j}}{\Gamma_{1,j}^2 + \omega^2} \\ & + \sin^2\theta_j \left[\frac{1 + \langle \rho_{z,j} \rangle}{2} \right] \frac{2\Gamma_{2,j}}{\Gamma_{2,j}^2 + (\omega - E_j)^2} \\ & + \sin^2\theta_j \left[\frac{1 - \langle \rho_{z,j} \rangle}{2} \right] \frac{2\Gamma_{2,j}}{\Gamma_{2,j}^2 + (\omega + E_j)^2}. \end{aligned} \quad (7)$$

In thermal equilibrium $\langle \rho_{z,j} \rangle = \tanh(E_j/2T)$. The first term, due to the longitudinal part of the coupling, describes random telegraph noise of a thermally excited TLS. We have assumed $\Gamma_{1,j} \ll T$, so that this term is symmetric (classical). The second term is due to the transverse coupling and describes absorption by the TLS, while the third

term describes the transitions of the TLS with emission. We observe that TLS's with $E_j \gg T$ contribute to C_X only at (positive) $\omega = E_j$. Indeed their contribution at $\omega = 0$ is suppressed by the thermal factor $1 - \langle \rho_{z,j} \rangle^2 = 1 - \tanh^2(E_j/2T)$. Also the negative frequency (emission) contribution at $\omega = -E_j$ is suppressed. These high-energy TLS's remain always in their ground state. Only the TLS's with $E_j < T$ are thermally excited, performing real random transitions between their two eigenstates, and contribute both at $\omega = \pm E_j$ and at $\omega = 0$. Such a multi-peaked structure of $C_j(\omega)$ was recently discussed in various contexts, e.g., in Refs. [25–27]. Note that the separation of the terms in Eq. (7) into low- and high-frequency noises is meaningful provided the typical width $\Gamma_{1,j}$ of the low- ω Lorentzians is lower than the high frequencies of interest, which are defined, e.g., by the qubit's level splitting or temperature.

For a dense distribution of the parameters ϵ , Δ , and v , we can evaluate the low- and high-frequency noises. For positive high frequencies, $\omega \gg T$, we obtain

$$\begin{aligned} C_X(\omega) & \approx \sum_j v_j^2 \sin^2\theta_j \frac{2\Gamma_{2,j}}{\Gamma_{2,j}^2 + (\omega - E_j)^2} \\ & \approx N \int d\epsilon d\Delta dv P(\epsilon, \Delta, v) v^2 \sin^2\theta \pi \delta(\omega - E), \end{aligned} \quad (8)$$

where N is the number of fluctuators, $P(\epsilon, \Delta, v)$ is the distribution function normalized to 1, $E \equiv \sqrt{\epsilon^2 + \Delta^2}$, and $\tan\theta = \Delta/\epsilon$. Without loss of generality we take $\epsilon \geq 0$ and $\Delta \geq 0$. At negative high frequencies ($\omega < 0$ and $|\omega| > T$) the correlator $C_X(\omega)$ is exponentially suppressed.

On the other hand, the total weight of the low-frequency (up to $\omega \sim \Gamma_{1,\text{max}}$) noise follows from the first term of (7). Each Lorentzian contributes 1. Thus we obtain

$$\begin{aligned} \int_{\text{low freq.}} \frac{d\omega}{2\pi} C_X(\omega) & \approx \int_{\text{low freq.}} \frac{d\omega}{2\pi} \sum_j v_j^2 \cos^2\theta_j [1 - \langle \rho_{z,j} \rangle^2] \\ & \quad \times \frac{2\Gamma_{1,j}}{\Gamma_{1,j}^2 + \omega^2} \\ & \approx N \int d\epsilon d\Delta dv P(\epsilon, \Delta, v) v^2 \\ & \quad \times \cos^2\theta \frac{1}{\cosh^2 \frac{E}{2T}}. \end{aligned} \quad (9)$$

In this Letter we consider only coherent TLS's, i.e., we assume that the maximum relaxation rate $\Gamma_{1,\text{max}}$ is smaller than the minimum energy splitting E_{min} of the TLS's. Thus the last two terms of (7) do not contribute to (9). The contribution of overdamped TLS's will be discussed elsewhere. Equations (8) and (9) provide the general framework for further discussion.

Next we investigate possible distributions for the parameters ϵ , Δ , and v . We consider a log-uniform distribution of tunnel splittings Δ , with density $P_\Delta(\Delta) \propto 1/\Delta$ in a

range $[\Delta_{\min}, \Delta_{\max}]$. This distribution is natural for TTLS's as Δ is an exponential function of an almost uniformly distributed parameter, e.g., tunnel barrier height [15]. It is also well-known to provide for the $1/f$ behavior of the low-frequency noise [8]: the relaxation rates are, then, also distributed log uniformly, $P_{\Gamma_1}(\Gamma_1) \propto 1/\Gamma_1$, and a sum of many Lorentzians of width Γ_1 centered at $\omega = 0$ adds up to the $1/f$ noise. We further assume that the distribution of ν is uncorrelated with ε and Δ .

First, we assume that the temperature is lower than Δ_{\max} , $T < \Delta_{\max}$. For the high-frequency part, $T < \omega < \Delta_{\max}$, taking the integral over Δ in Eq. (8), we find that

$$C_X(\omega) \propto \frac{1}{\omega} \int_0^\omega P_\varepsilon(\varepsilon) d\varepsilon. \quad (10)$$

This is consistent with an Ohmic behavior $C_X \propto \omega$ only for the linear density $P_\varepsilon(\varepsilon) \propto \varepsilon$.

Importantly, this distribution $P(\varepsilon, \Delta) \propto \varepsilon/\Delta$ leads at the same time to the $T^2 \ln(T/\Delta_{\min})$ behavior of the low-frequency weight (9), consistent with experimental observations [3–6]. If the low-frequency noise has a $1/f$ dependence, the two parts of the spectrum would cross around $\omega \sim T$ [2].

A remark is in order concerning this crossing. It is not guaranteed that the spectrum has a $1/f$ dependence up to $\omega \sim T$. Rather the high-frequency cutoff of the low-frequency $1/f$ noise is given by the maximum relaxation rate of the TLS's, $\Gamma_{1,\max} \ll T$, as we assumed. Then the *extrapolations* of the low-frequency $1/f$ and high-frequency Ohmic spectra cross at this $\omega \sim T$.

To fix the coefficients, we introduce the normalization constant A , so that $P(\varepsilon, \Delta) = A\varepsilon/\Delta$. Then, at high positive frequencies, $T < \omega < \Delta_{\max}$, we obtain

$$C_X(\omega) \approx \pi \langle \nu^2 \rangle N A \omega. \quad (11)$$

For the total weight of the low-frequency noise we obtain

$$\int_{\text{low freq.}} \frac{d\omega}{2\pi} C_X(\omega) \approx 4 \ln(2) \langle \nu^2 \rangle N A T^2 \left[\ln \frac{T}{\Delta_{\min}} \right]. \quad (12)$$

Thus we obtain a numerical factor which determines precisely the point of crossing of the two spectra.

In the opposite limit, $T \gg \Delta_{\max}$, the high-frequency noise depends on the detailed shape of the cutoff of $P_\Delta(\Delta)$ at Δ_{\max} . As an example, for a hard cutoff the Ohmic spectral density implies that $P_\varepsilon \propto \varepsilon^3$, and the low-frequency weight scales with T^4 . For a $1/f$ low-frequency behavior, the spectra would cross at $\omega \sim T^2/\Delta_{\max} \gg T$, in disagreement with the result of Ref. [2].

Interestingly, the linear ω dependence at high frequencies and the T^2 dependence of the low-frequency noise can be obtained from a whole class of distributions, e.g., for $P(\varepsilon, \Delta) = f(\varepsilon/\Delta)$, with arbitrary, not too divergent (as a function of θ) function f . Presented as a function of energy

E and angle θ , it becomes (we have used the Jacobian $d\varepsilon d\Delta \rightarrow E dE d\theta$)

$$P(E, \theta) = E f(\cot\theta); \quad (13)$$

i.e., it is linear in E . This linearity ensures both the linear ω dependence at high frequencies and the T^2 dependence of the integrated weight of the low-frequency noise.

In particular, one can take $P(\varepsilon, \Delta) \propto (\varepsilon/\Delta)^s$ with any exponent s satisfying $-1 \leq s \leq 1$, and with both Δ_{\max} and ε_{\max} higher than the relevant frequency ω . This includes a uniform distribution of both Δ and ε at all relevant energies, i.e., $s = 0$. For ensembles with $-1 < s < 1$, including the uniform distribution with $s = 0$, high- and low-frequency noises are created by the same fluctuators. On the other hand, $s = 1$ is the limiting case in which the low-frequency noise is dominated by the fluctuators with $\theta \ll 1$, while the high-frequency noise by all other fluctuators. Yet, even in this case the strengths of the high- and low-frequency parts of the spectrum are related.

For the uniform distribution ($s = 0$) we obtain different numerical coefficients. We introduce an experimentally accessible constant α , such that $C_X(\omega \gg T) = 2\pi\alpha\omega$. Then, for $s = 1$ ($P \propto \varepsilon/\Delta$) we obtain from Eqs. (11) and (12) that the total weight of the low-frequency noise is given by $\int_{\text{low freq.}} \frac{d\omega}{2\pi} C_X(\omega) \approx 8 \ln(2) \alpha T^2 \ln(T/\Delta_{\min})$. On the other hand, for the uniform distribution, $s = 0$, we obtain $\int_{\text{low freq.}} \frac{d\omega}{2\pi} C_X(\omega) \approx 4 \ln(2) \alpha T^2$.

We emphasize that the relation between low- and high-frequency noises is more general; i.e., it is not unique to an ensemble of two-level systems. Consider an ensemble of many-level systems with levels $|n\rangle$ and energies E_n such that the coupling is via an observable which has both transverse and longitudinal components. By a transverse component we mean the part constructed with operators $|n\rangle\langle m|$, where $n \neq m$, while the longitudinal component is built from the projectors $|n\rangle\langle n|$. If the system is underdamped, that is, if the absorption and emission lines are well defined, the correlator of such an observable will have (Lorentzian-like) contributions at $\omega = E_n - E_m$ as well as at $\omega = 0$. As an example we could consider an ensemble of anharmonic oscillators with $X = \sum_j \nu_j x_j$, where x_j are the oscillator's coordinates. Because of the anharmonicity x_j acquires a longitudinal component, in addition to the usual transverse one. Thus a relation between the low- and high-frequency noises would emerge naturally with details depending on the ensemble statistics.

It is useful to relate our phenomenological results to the recent work of Faoro *et al.* [7], where they considered physical models of the fluctuators, which could couple to and relax qubits. They considered three models: (I) a single-electron trap in tunnel contact with a metallic gate, (II) a single electron occupying a double trap, and (III) a double trap that can absorb or emit a Cooper pair from the qubit or a superconducting gate. In all models a uniform distribution of the trap energy levels was assumed.

One, then, can show that the distribution for the two-level systems corresponding to the models II and III are linear in the energy level splitting, $P(\epsilon) \propto \epsilon$. Since the switching in these models is tunneling dominated, we find that $P(\Delta) \propto 1/\Delta$. Therefore, both models II and III are characterized by distribution $P(\epsilon, \Delta) = A\epsilon/\Delta$, described above, and hence can naturally account for the experimentally observed low- and high-frequency noises. In contrast, in the model of uniformly distributed single-electron traps (model I), we find that for small tunnel rates, the high-frequency noise is inversely proportional to frequency rather than Ohmic [7].

In this Letter we did not address the question of the statistics of the low-frequency noise nor the associated problem of a particular decay law of the dephasing process. These statistics will depend on the distribution of the coupling strengths ν_j . For certain distributions the individual strongly coupled fluctuators may be important [28,29], and the statistics is non-Gaussian. For ensembles of many weakly coupled fluctuators Gaussian statistics emerges [11,30].

To conclude, we have shown that an ensemble of coherent two-level systems with the distribution function, $P(\epsilon, \Delta) \propto \epsilon/\Delta$, produces Ohmic high-frequency noise and, at the same time, $1/f$ low-frequency noise with strength which grows with temperature as T^2 . The two branches of the noise power cross at $\omega \sim T$ in accordance with the experimental observation [2]. A relation between low- and high-frequency parts of the spectrum is a general property of ensembles of coherent systems with discrete energy levels.

We are grateful to Yu. A. Pashkin for communicating the experimental results of Ref. [2] prior to publication. We thank J. Clarke and O. Astafiev for stimulating discussions and useful comments. The work is part of the CFN of the DFG and of the EU IST Project SQUBIT. This work was supported by the U.S. DOE, by the A. v. Humboldt Foundation, and by the Dynasty Foundation.

-
- [1] R. W. Simmonds, K. M. Lang, D. A. Hite, S. Nam, D. P. Pappas, and J. M. Martinis, Phys. Rev. Lett. **93**, 077003 (2004).
 - [2] O. Astafiev, Yu. A. Pashkin, Y. Nakamura, T. Yamamoto, and J. S. Tsai, Phys. Rev. Lett. **93**, 267007 (2004).
 - [3] F. C. Wellstood, Ph.D. thesis, University of California–Berkeley, 1988.
 - [4] M. Kenyon, C. J. Lobb, and F. C. Wellstood, J. Appl. Phys. **88**, 6536 (2000).

- [5] O. Astafiev *et al.* (private communication).
- [6] F. C. Wellstood, C. Urbina, and J. Clarke, Appl. Phys. Lett. **85**, 5296 (2004).
- [7] L. Faoro, J. Bergli, B. A. Altshuler, and Y. M. Galperin, cond-mat/0411425.
- [8] P. Dutta and P. M. Horn, Rev. Mod. Phys. **53**, 497 (1981).
- [9] G. Zimmerli, T. M. Eiles, R. L. Kautz, and J. M. Martinis, Appl. Phys. Lett. **61**, 237 (1992).
- [10] A. B. Zorin, F.-J. Ahlers, J. Niemeyer, T. Weimann, H. Wolf, V. A. Krupenin, and S. V. Lotkhov, Phys. Rev. B **53**, 13 682 (1996).
- [11] Y. Nakamura, Yu. A. Pashkin, T. Yamamoto, and J. S. Tsai, Phys. Rev. Lett. **88**, 047901 (2002).
- [12] D. Vion, A. Aassime, A. Cottet, P. Joyez, H. Pothier, C. Urbina, D. Esteve, and M. H. Devoret, Science **296**, 886 (2002).
- [13] D. J. VanHarlingen, T. L. Robertson, B. L. T. Plourde, P. A. Reichardt, T. A. Crane, and J. Clarke, Phys. Rev. B **70**, 064517 (2004).
- [14] P. W. Anderson, B. I. Halperin, and C. M. Varma, Philos. Mag. **25**, 1 (1972).
- [15] W. A. Phillips, J. Low Temp. Phys. **7**, 351 (1972).
- [16] J. L. Black, in *Glassy Metals*, edited by H.-J. Güntherodt and H. Beck (Springer-Verlag, Berlin, 1981).
- [17] Y. Imry, H. Fukuyama, and P. Schwab, Europhys. Lett. **47**, 608 (1999).
- [18] S. M. Kogan and K. E. Nagaev, Solid State Commun. **49**, 387 (1984).
- [19] A. Ludviksson, R. Kree, and A. Schmid, Phys. Rev. Lett. **52**, 950 (1984).
- [20] S. Feng, P. A. Lee, and A. D. Stone, Phys. Rev. Lett. **56**, 1960 (1986).
- [21] R. Aguado and L. P. Kouwenhoven, Phys. Rev. Lett. **84**, 1986 (2000).
- [22] R. J. Schoelkopf, A. A. Clerk, S. M. Girvin, K. W. Lehnert, and M. H. Devoret, in *Quantum Noise in Mesoscopic Physics*, edited by Yuli V. Nazarov, NATO Science Series, Ser. II (Kluwer Academic Publishers, Dordrecht, Boston, 2003), pp. 175–203.
- [23] F. Bloch, Phys. Rev. **105**, 1206 (1957).
- [24] A. G. Redfield, IBM J. Res. Dev. **1**, 19 (1957).
- [25] A. N. Korotkov and D. V. Averin, Phys. Rev. B **64**, 165310 (2001).
- [26] A. Shnirman, D. Mozyrsky, and I. Martin, Europhys. Lett. **67**, 840 (2004).
- [27] Y. M. Galperin, V. I. Kozub, and V. M. Vinokur, Phys. Rev. B **70**, 033405 (2004).
- [28] E. Paladino, L. Faoro, G. Falci, and R. Fazio, Phys. Rev. Lett. **88**, 228304 (2002).
- [29] Y. M. Galperin, B. L. Altshuler, and D. V. Shantsev, cond-mat/0312490.
- [30] A. Shnirman, Yu. Makhlin, and G. Schön, Phys. Scr. **T102**, 147 (2002).